

High Power LED

BL-HP9EXX

Features:

- ∅ 1W LEDs , suitable for illumination lamps and decorative lighting
- ∅ Longer service and less luminosity loss, 50,000hours
- ∅ Different emitting colors are available Working current: 200-350mA
- ∅ With or without heat sink are both available

Applications:

Commercial lighting
Residential lighting
Decorative lighting



1Watt Lambertian

Electrical-optical characteristics: (Ta=25°C)

Part Number	Chip		Lens Type	Forward Voltage(VF) Unit: V		Flux Unit:lm		Viewing Angle 2θ/2 (deg)
	Emitted Color	λ _p (nm) or CTT		Typ	Max	Min.	Typ.	
				Water Clear				
BL-HP9EUEC	Ultra Orange	630		2.2	2.75	35	45	
BL-HP9EUYC	Ultra Yellow	590		2.2	2.75	35	45	
BL-HP9EPGC	Ultra Pure Green	525		3.2	3.8	50	60	
BL-HP9EBGC	Ultra Bluish Green	505		3.2	3.8	40	50	
BL-HP9EUBC	Ultra Blue	470		3.2	3.8	10	15	
BL-HP9EUWC	Ultra White	6000k		3.2	3.8	70	90	
BL-HP9EUW2C	Ultra Warm White	3200k		3.2	3.8	50	70	

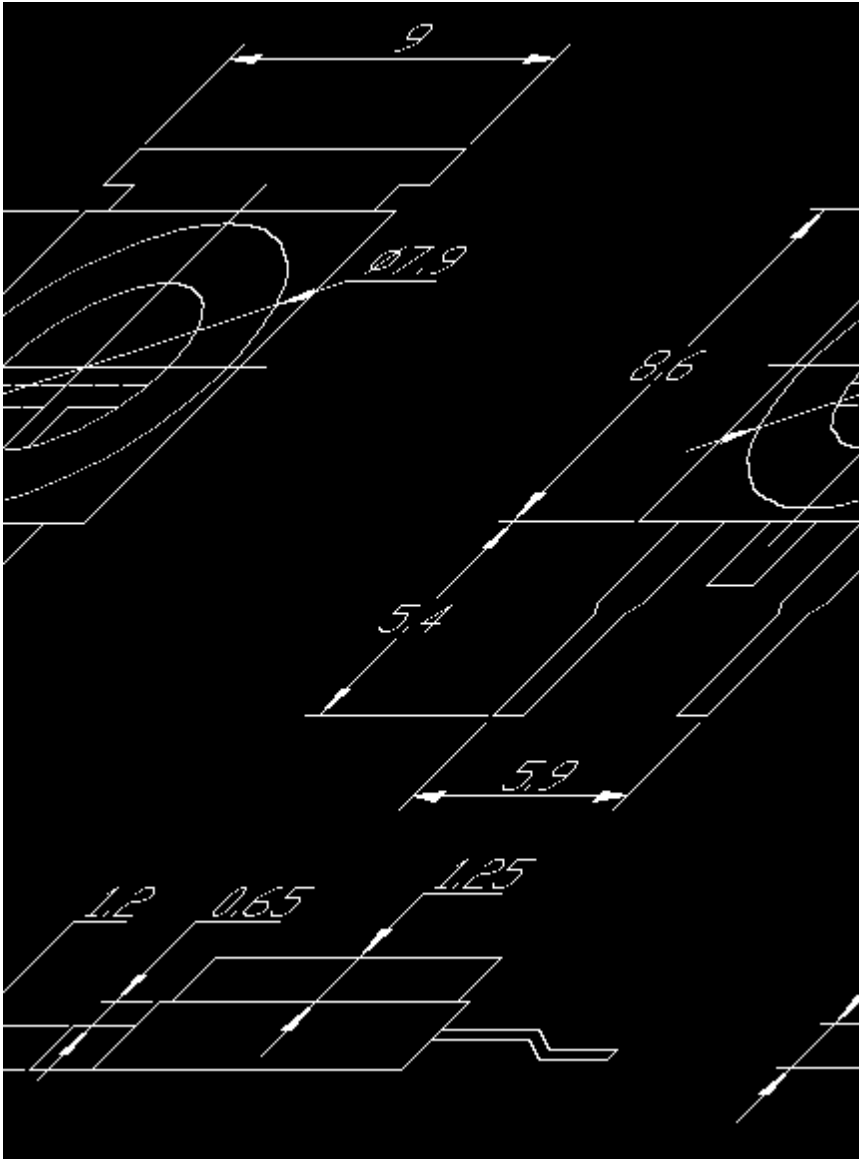
Absolute maximum ratings (Ta=25°C)

Parameter	UE	UY	BG	PG	UB	UW	Unit
Forward Current I _F	350	350	350	350	350	350	mA
LED Junction Temperature	120	120	120	120	120	120	°C
Peak Forward Current I _{PF} (Duty 1/10 @1KHZ)	500	500	500	500	500	500	mA
Operation Temperature T _{OPR}	-40 to +80						°C
Storage Temperature T _{STG}	-40 to +100						°C
Aluminum-Core Pcb Temperature	105						°C

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Package configuration & Internal circuit diagram



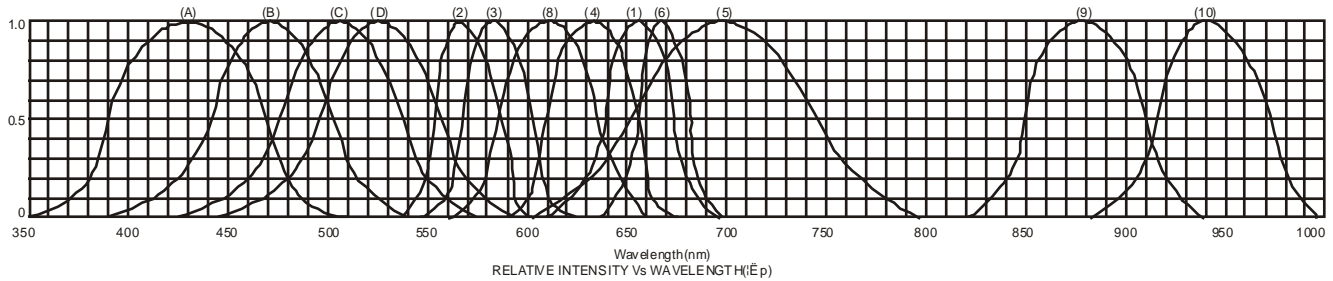
Notes:

1. All dimensions are in millimeters (inches)
2. Tolerance is 0.25(0.01")unless otherwise noted.
3. Specifications are subject to change without notice.

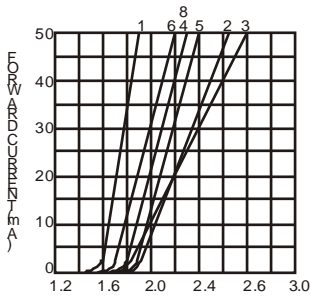
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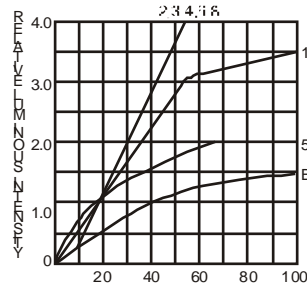
Typical electrical-optical characteristics curves:



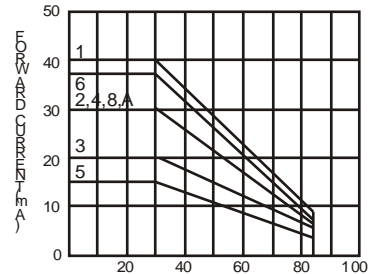
- (1) - GaAsP/GaAs 655nm/Red
- (2) - GaP 570nm/Yellow Green
- (3) - GaAsP/GaP 585nm/Yellow
- (4) - GaAsP/GaP 635nm/Orange & Hi-Eff Red
- (5) - GaP 700nm/Bright Red
- (6) - GaAlAs/GaAs 660nm/Super Red
- (8) - GaAsP/GaP 610nm/Super Red
- (9) - GaAlAs 880nm
- (10) - GaAs/GaAs & GaAlAs/GaAs 940nm
- (A) - GaN/SiC 430nm/Blue
- (B) - InGaN/SiC 470nm/Blue
- (C) - InGaN/SiC 505nm/Ultra Green
- (D) - InGaAlSiC 525nm/Ultra Green



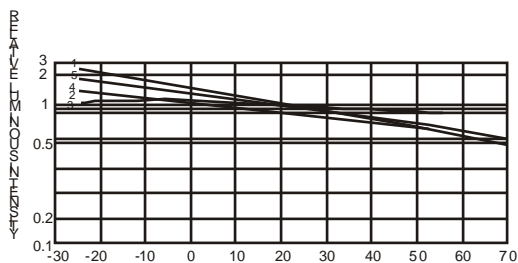
FORWARD VOLTAGE (Vf)
FORWARD CURRENT VS.
FORWARD VOLTAGE



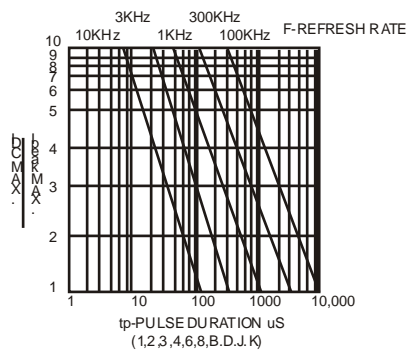
FORWARD CURRENT (mA)
RELATIVE LUMINOUS
INTENSITY VS. FORWARD
CURRENT



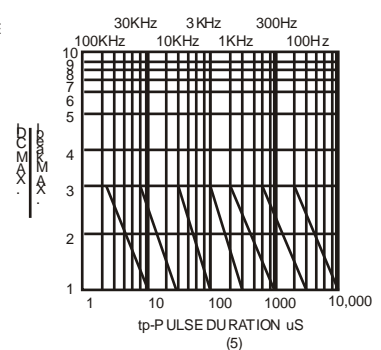
AMBIENT TEMPERATURE Ta (°C)
FORWARD CURRENT VS. AMBIENT
TEMPERATURE



AMBIENT TEMPERATURE Ta (°C)



tp-PULSE DURATION μs
(1,2,3,4,6,8,B,D,J,K)



tp-PULSE DURATION μs
(5)

NOTE: 25 free air temperature unless otherwise specified

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Packing and weighting

